

# Contents

LIST OF CONTRIBUTORS	ix
PREFACE	xi
<b>Chapter 1 Information Capacity of Condensed Systems</b>	<b>1</b>
<i>M. D. Bal'makov</i>	
1. EXACT COPY	2
2. DESCRIPTION IN THE FRAMEWORK OF THE ADIABATIC APPROXIMATION	5
3. ESTIMATION OF THE NUMBER OF DIFFERENT QUASICLOSED ENSEMBLES	8
4. DEFINITION OF A QUASICLOSED ENSEMBLE	10
5. CONCLUSION	11
REFERENCES	13
<b>Chapter 2 Charge Carrier Transfer at High Electric Fields in Noncrystalline Semiconductors</b>	<b>15</b>
<i>A. Česnys, G. Juška and E. Montrimas</i>	
1. INTRODUCTION	15
2. CHARGE TRANSFER IN NONCRYSTALLINE SELENIUM AND AS-SE SYSTEM THIN FILMS	17
2.1. <i>Amorphous Selenium Electrical Conduction Dependence on Impurities</i>	17
2.2. <i>Temperature and Electric Field Dependencies of Charge Carrier Drift and Micromobility</i>	19
2.3. <i>Multiplication Effect in Amorphous Selenium</i>	20
2.4. <i>Influence of Chemical Composition on Charge Transfer in As-Se System Thin Films</i>	24
2.5. <i>Space Charge Formation and Distribution in As-Se System Thin Films</i>	30
3. ELECTRICAL CHARGE TRANSPORT IN NONCRYSTALLINE Ga(OR In)-Te SYSTEMS STRUCTURES	39
3.1. <i>A Variety of Electrical Conductivity in Barrier-less Structures</i>	39
3.2. <i>Nonactivated Electrical Conduction State</i>	46
3.3. <i>Electrical Characteristics of Barrier Structures</i>	50
REFERENCES	52

<b>Chapter 3</b>	<b>The Nature of the Current Instability in Chalcogenide Vitreous Semiconductors</b>	<b>57</b>
<i>Andrey S. Glebov</i>		
1.	INTRODUCTION	57
2.	CURRENT CHANNELS IN CVS-BASED SWITCHES	58
2.1.	<i>Models of Generation of Current Channels at Presence of Drift Barriers in CVS</i>	67
2.2.	<i>Dimensional Effects in CVS-based Switches</i>	71
3.	THE KINETIC MODEL OF THE CURRENT INSTABILITY AT THE PRESENCE OF THE CURRENT CHANNEL	77
4.	EXPERIMENTAL CONFIRMATION OF THE KINETIC MODEL OF THE SWITCHING EFFECT	85
4.1.	<i>Influence of CVS Composition on Functional Characteristics of Switches</i>	85
4.2.	<i>Dependence of Electro-physical Parameters of Switches from Temperature and Pressure</i>	97
4.3.	<i>Influence of Synthesis and Thermal Treatment Conditions on Physical-Chemical Properties of Glasses and Electrical Parameters of Mono-stable Switches</i>	105
	REFERENCES	109
<b>Chapter 4</b>	<b>Optical and Photoelectrical Properties of Chalcogenide Glasses</b>	<b>115</b>
<i>A. M. Andriesh, M. S. Iovu and S. D. Shutov</i>		
1.	OPTICAL PROPERTIES OF CHALCOGENIDE GLASSES	115
1.1.	<i>The Reflectivity Spectra of Chalcogenide Crystals and Glasses: Electron States</i>	116
1.2.	<i>The Absorption Edge in Amorphous Chalcogenides</i>	121
1.3.	<i>Photo-induced Absorption</i>	138
2.	PHOTOELECTRICAL PROPERTIES OF AMORPHOUS CHALCOGENIDES	149
2.1.	<i>Steady-state Photoconductivity</i>	149
2.2.	<i>Transient Photoconductivity</i>	168
3.	CHALCOGENIDE GLASSES IN PHOTOELECTRIC INFORMATION RECORDING SYSTEMS	179
3.1.	<i>Chalcogenide Glasses for Integrated and Fiber Optics Application</i>	179
	REFERENCES	193
<b>Chapter 5</b>	<b>Optical Spectra of Arsenic Chalcogenides in a Wide Energy Range of Fundamental Absorption</b>	<b>201</b>
<i>V. Val. Sobolev and V. V. Sobolev</i>		
1.	INTRODUCTION	201
2.	THE GENERAL CONSIDERATION OF OPTICAL SPECTRA AND ELECTRONIC STRUCTURE THEORY	202
3.	MEASUREMENT TECHNIQUES AND DETERMINATION OF SPECTRA OF OPTICAL FUNCTIONS AND DENSITY OF STATES DISTRIBUTION $N(E)$	204
4.	OPTICAL SPECTRA OF $\alpha$ -As <sub>2</sub> S <sub>3</sub>	205
4.1.	<i>Calculations of Sets of Optical Functions</i>	205
4.2.	<i>Decomposition of Dielectric Function Spectra and Characteristic Electron Loss Spectra into Elementary Components</i>	208
5.	OPTICAL SPECTRA OF $g$ -As <sub>2</sub> Se <sub>3</sub>	212
5.1.	<i>Calculations of Sets of Optical Functions</i>	212
5.2.	<i>Decomposition of Dielectric Function Spectra and Characteristic Electron Loss Spectra into Elementary Components</i>	217
6.	OPTICAL SPECTRA OF $g$ -As <sub>x</sub> Se <sub>1-x</sub> ( $x = 0.5, 0.36$ )	219
6.1.	<i>Calculations of Sets of Optical Functions</i>	219

6.2. <i>Decomposition of Dielectric Function Spectra and Characteristic Electron Loss Spectra into Elementary Components</i>	222
7. OPTICAL SPECTRA OF $g\text{-As}_2\text{Te}_3$	224
7.1. <i>Calculations of Sets of Optical Functions</i>	224
7.2. <i>Decomposition of Dielectric Function Spectra and Characteristic Electron Loss Spectra into Elementary Components</i>	226
8. CONCLUSION	227
REFERENCES	227

## Chapter 6 Magnetic Properties of Chalcogenide Glasses 229

*Yu. S. Tver'yanovich*

1. MAGNETISM OF CHALCOGENIDE GLASSES NOT CONTAINING TRANSITIONAL METALS	229
1.1. <i>Problems of Physicochemical Analysis of Glassy Systems</i>	229
1.2. <i>Dorfman's Method</i>	230
1.3. <i>Application of Magneto-chemistry for PCA</i>	231
2. MAGNETISM OF GLASS-FORMING MELTS	232
2.1. <i>Magnetism of Chalcogenide Glasses at Heating</i>	232
2.2. <i>Melts</i>	235
2.3. <i>Magnetism of Melts with Low Conductivity</i>	235
2.4. <i>Semiconductor-Metal Transition in Chalcogenide Melts</i>	238
2.5. <i>Metallized State</i>	243
2.6. <i>Dependencies of Magnetic Susceptibility of Chalcogenide Melts on Composition and Temperature</i>	244
2.7. <i>Semiconductor-Metal Transition and Glass-Forming Ability of Chalcogenide Melts</i>	247
3. CHALCOGENIDE GLASSES CONTAINING TRANSITIONAL METALS	248
3.1. <i>The Degree of Oxidizing of Transitional Metals in Chalcogenide Glasses</i>	249
3.2. <i>The Model of Magnetism of Glasses Containing Transitional Metals</i>	249
3.3. <i>The Results of the Investigations of Magnetic Properties of Chalcogenide Glasses, Containing Transitional Metals</i>	257
3.4. <i>Using of the Result of Magneto-chemical Investigations at the Modeling of Electrical Properties of Chalcogenide Glasses, Doped with Transitional Metals</i>	265
4. MAGNETIC PROPERTIES OF GLASS-FORMING CHALCOGENIDE ALLOYS AT MELTING	266
4.1. <i>Equation Using Results of Magnetic Experience for the Calculation of Liquidus</i>	266
4.2. <i>System <math>\text{As}_2\text{Se}_3\text{-MnSe}</math></i>	269
4.3. <i>Liquidus for Other Chalcogenide Systems Doped with Transitional Metals</i>	270
REFERENCES	274
INDEX	277
CONTENTS OF VOLUMES IN THIS SERIES	285